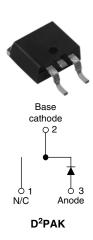


## Vishay High Power Products

# HEXFRED® Ultrafast Soft Recovery Diode, 8 A



PRODUCT SUMMARY				
$V_{R}$	1200 V			
V <sub>F</sub> at 8 A at 25 °C	3.3 V			
I <sub>F(AV)</sub>	8 A			
t <sub>rr</sub> (typical)	28 ns			
T <sub>J</sub> (maximum)	150 °C			
Q <sub>rr</sub> (typical)	140 nC			
dI <sub>(rec)M</sub> /dt (typical) at 125 °C	85 A/μs			
I <sub>RRM</sub> (typical)	4.5 A			

#### **FEATURES**

- Ultrafast recovery
- · Ultrasoft recovery
- Very low I<sub>RRM</sub>
- Very low Q<sub>rr</sub>
- · Specified at operating conditions
- Compliant to RoHS directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- AEC-Q101 qualified





RoHS\*

HALOGEN FREE

#### **BENEFITS**

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- · Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

#### **DESCRIPTION**

HFA08TB120S is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 8 A continuous current, the HFA08TB120S is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I<sub>RRM</sub>) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA08TB120S is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	$V_R$		1200	V	
Maximum continuous forward current	I <sub>F</sub>	T <sub>C</sub> = 100 °C	8		
Single pulse forward current	I <sub>FSM</sub>		130	Α	
Maximum repetitive forward current	I <sub>FRM</sub>		32		
Maximum power dissipation	P <sub>D</sub>	T <sub>C</sub> = 25 °C	73.5	W	
Maximum power dissipation		T <sub>C</sub> = 100 °C	29	VV	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to + 150	°C	

<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply

## HFA08TB120SPbF

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<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	V <sub>BR</sub>	Ι <sub>R</sub> = 100 μΑ	1200	-	-		
		I <sub>F</sub> = 8.0 A	-	2.6	3.3	V	
Maximum forward voltage V <sub>FM</sub>	I <sub>F</sub> = 16 A	-	3.4	4.3			
		I <sub>F</sub> = 8.0 A, T <sub>J</sub> = 125 °C	-	2.4	3.1		
Maximum reverse		$V_R = V_R$ rated	-	0.31	10		
leakage current		$T_J = 125 ^{\circ}\text{C},  V_R = 0.8 ^{\circ}\text{x} ^{\circ}\text{V}_R ^{\circ}\text{rated}$	-	135	1000	μΑ	
Junction capacitance	Ст	V <sub>R</sub> = 200 V	-	11	20	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	28	-	
Reverse recovery time	t <sub>rr1</sub>	T <sub>J</sub> = 25 °C		-	63	95	ns
	t <sub>rr2</sub>	T <sub>J</sub> = 125 °C	$I_F = 8.0 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$	-	106	160	
Peak recovery current	I <sub>RRM1</sub>	T <sub>J</sub> = 25 °C		-	4.5	8.0	A
	I <sub>RRM2</sub>	T <sub>J</sub> = 125 °C		-	6.2	11	
D	Q <sub>rr1</sub>	T <sub>J</sub> = 25 °C		-	140	380	nC
Reverse recovery charge	Q <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	335	880	
	dI <sub>(rec)M</sub> /dt1	T <sub>J</sub> = 25 °C		-	133	-	A/μs
	dI <sub>(rec)M</sub> /dt2	T <sub>J</sub> = 125 °C		-	85	-	Ανμδ

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	L TEST CONDITIONS		TYP.	MAX.	UNITS
Lead temperature	T <sub>lead</sub>	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	1.7	K/W
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	N/W
Weight			-	2.0	-	g
Weight			-	0.07	-	OZ.
Marking device		Case style D <sup>2</sup> PAK		HFA08	TB120S	

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95046</u>				
Part marking information	www.vishay.com/doc?95054			
Packaging information	www.vishay.com/doc?95032			

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